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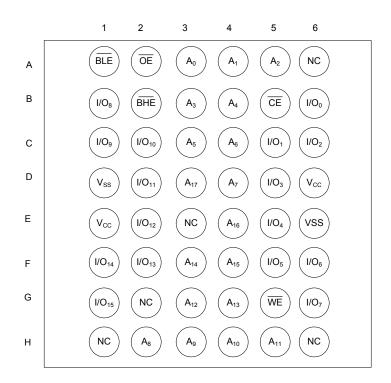
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Pin Configuration

Figure 1. 48 ball BGA pinout [1]



Selection Guide

Description	-10	Unit	
Maximum access time		10	ns
Maximum operating current Aut	tomotive-E	130	mA
Maximum CMOS standby current Aut	tomotive-E	15	mA

Note

^{1.} NC pins are not connected on the die.



Maximum Ratings

DC input voltage [2]	0.5 V to V _{CC} + 0.5 V
Current into outputs (LOW)	20 mA
Static discharge voltage (MIL-STD-883, method 3015)	> 2001 V
Latch up current	> 200 mA

Operating Range

Range	Ambient Temperature (T _A)	V _{CC}	
Automotive-E	–40 °C to +125 °C	$3.3~V\pm10\%$	

Electrical Characteristics

Over the Operating Range

Doromotor	Decarintian	Test Condition	Test Conditions			Unit
Parameter	Description	rest Conditions	rest conditions		Max	Oilit
V _{OH}	Output HIGH voltage	$V_{\rm CC}$ = Min, $I_{\rm OH}$ = -4.0 mA		2.4	_	V
V_{OL}	Output LOW voltage	V_{CC} = Min, I_{OL} = 8.0 mA		-	0.4	V
V_{IH}	Input HIGH voltage			2.0	V _{CC} + 0.3	V
V _{IL}	Input LOW voltage [2]			-0.3	0.8	V
I _{IX}	Input leakage current	$GND \le V_1 \le V_{CC}$	-20	+20	μΑ	
I _{OZ}	Output leakage current	$\begin{aligned} & \text{GND} \leq V_{\text{I}} \leq V_{\text{CC}}, \\ & \text{Output disabled} \end{aligned}$	Automotive-E	-20	+20	μА
Icc	V _{CC} operating supply current	V_{CC} = Max, I_{OUT} = 0 mA, f = f_{MAX} = 1/ t_{RC}	Automotive-E	-	130	mA
I _{SB1}	Automatic CE power down current – TTL Inputs	$\begin{aligned} &\text{Max V}_{\text{CC}}, \overline{\text{CE}} \geq \text{V}_{\text{IH}}, \\ &\text{V}_{\text{IN}} \geq \text{V}_{\text{IH}} \text{ or V}_{\text{IN}} \leq \text{V}_{\text{IL}}, \text{f} = \text{f}_{\text{MAX}} \end{aligned}$	Automotive-E	_	45	mA
I _{SB2}	Automatic CE power down current – CMOS inputs	$\begin{array}{l} \text{Max V}_{CC}, \ \overline{\text{CE}} \geq \text{V}_{CC} - 0.3 \ \text{V}, \\ \text{V}_{\text{IN}} \geq \text{V}_{CC} - 0.3 \ \text{V}, \ \text{or} \\ \text{V}_{\text{IN}} \leq 0.3 \ \text{V}, \ \text{f} = 0 \end{array}$	Automotive-E	_	15	mA

Note

^{2.} V_{IL} (min) = -2.0 V for pulse durations of less than 20 ns.



Capacitance

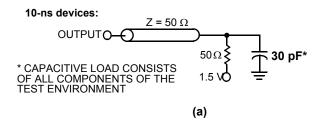
Parameter [3]	Description	Test Conditions	Max	Unit
C _{IN}	Input capacitance	$T_A = 25 ^{\circ}\text{C}, f = 1 \text{MHz}, V_{CC} = 3.3 \text{V}$	8	pF
C _{OUT}	Output capacitance		8	pF

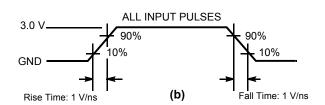
Thermal Resistance

Parameter [3]	Description	Test Conditions	48-ball BGA	Unit
Θ_{JA}	Thermal resistance (junction to ambient)	Still air, soldered on a 3 × 4.5 inch, four-layer printed circuit board	38.15	°C/W
Θ_{JC}	Thermal resistance (junction to case)		9.15	°C/W

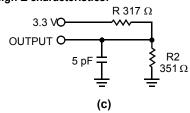
AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms [4]





High-Z characteristics:



Notes

- ${\it 3. \ \ } Tested \ initially \ and \ after \ any \ design \ or \ process \ changes \ that \ may \ affect \ these \ parameters.$
- 4. AC characteristics (except High Z) for 10-ns parts are tested using the load conditions shown in Figure 2 (a). High Z characteristics are tested using the test load shown in Figure 2 (c).



Switching Characteristics

Over the Operating Range

D [5]	Book to the	-	10	11.14
Parameter [5]	Description	Min	Max	Unit
Read Cycle		<u>.</u>		
t _{power} ^[6]	V _{CC} (typical) to the first access	100	_	μS
t _{RC}	Read cycle time	10	_	ns
t _{AA}	Address to data valid	_	10	ns
t _{OHA}	Data hold from address change	3	_	ns
t _{ACE}	CE LOW to data valid	_	10	ns
t _{DOE}	OE LOW to data valid	_	6	ns
t _{LZOE}	OE LOW to Low Z [7]	0	_	ns
t _{HZOE}	OE HIGH to High Z [7, 8]	_	5	ns
t _{LZCE}	CE LOW to Low Z [7]	3	_	ns
t _{HZCE}	CE HIGH to High Z [7, 8]	_	5	ns
t _{PU}	CE LOW to power up	0	_	ns
t _{PD}	CE HIGH to power down	_	10	ns
t _{DBE}	Byte enable to data valid	_	6	ns
t _{LZBE}	Byte enable to Low Z	0	_	ns
t _{HZBE}	Byte disable to High Z	_	6	ns
Write Cycle [9,	10]			
t _{WC}	Write cycle time	10	_	ns
t _{SCE}	CE LOW to write end	7	_	ns
t _{AW}	Address setup to write end	7	_	ns
t _{HA}	Address hold from write end	0	_	ns
t _{SA}	Address setup to write start	0	-	ns
t _{PWE}	WE pulse width	7	_	ns
t _{SD}	Data setup to write end	5	_	ns
t _{HD}	Data hold from write end	0	_	ns
t _{LZWE}	WE HIGH to Low Z [7]	3	_	ns
t _{HZWE}	WE LOW to High Z [7, 8]	_	5	ns
t _{BW}	Byte enable to end of write	7	_	ns

- 5. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V.

 6. t_{POWER} gives the minimum amount of time that the power supply is at typical V_{CC} values until the first memory access is performed.

 7. At any temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} for any device.

 8. t_{HZOE}, t_{HZBE}, t_{HZCE}, and t_{HZWE} are specified with a load capacitance of 5 pF as in part (c) of Figure 2 on page 5. Transition is measured ±500 mV from steady state voltage.

 9. The internal write time of the memory is defined by the overlap of CE LOW, WE LOW, and BHE/BLE LOW. CE, WE, and BHE/BLE must be LOW to initiate a write. The transition of these signals terminate the write. The input data setup and hold timing is referenced to the leading edge of the signal that terminates the write.

 10. The minimum write cycle time for Write Cycle No. 3 (WE controlled, OE LOW) is the sum of t_{HZWE} and t_{SD}.



Switching Waveforms

Figure 3. Read Cycle No. 1 (Address Transition Controlled) [11, 12]

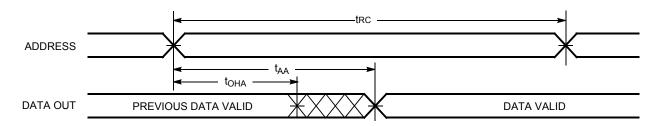
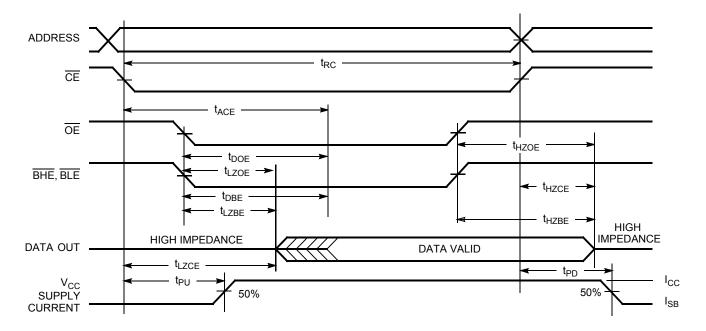


Figure 4. Read Cycle No. 2 (OE Controlled) [12, 13]



Notes

^{11. &}lt;u>Device</u> is continuously selected. \overline{OE} , \overline{CE} , \overline{BHE} , and/or $\overline{BLE} = V_{IL}$.

^{12.} WE is HIGH for read cycle.

^{13.} Address valid prior to or coincident with $\overline{\text{CE}}$ transition LOW.



Switching Waveforms (continued)

Figure 5. Write Cycle No. 1 (CE Controlled) [14, 15]

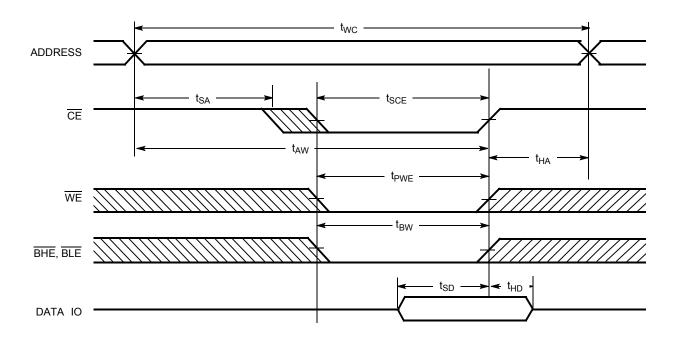
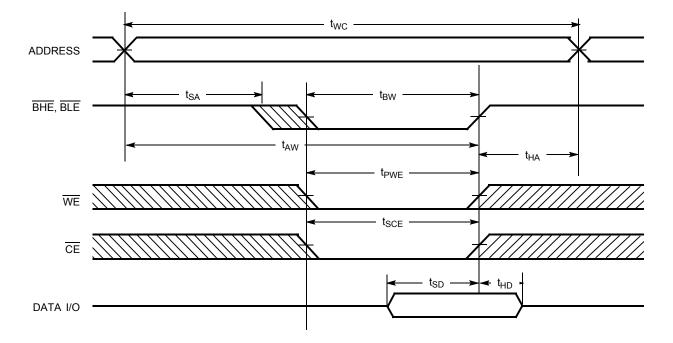


Figure 6. Write Cycle No. 2 (BLE or BHE Controlled)



Notes

^{14.} Data I/O is high impedance if OE, BHE, and/or BLE = V_{IH}.

15. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.



Switching Waveforms (continued)

ADDRESS

CE

tsce

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Figure 7. Write Cycle No. 3 (WE Controlled, LOW)



Truth Table

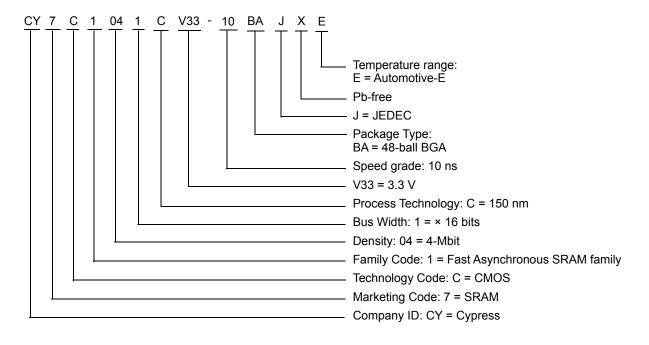
CE	OE	WE	BLE	BHE	I/O ₀ –I/O ₇	I/O ₈ -I/O ₁₅	Mode	Power
Н	Х	Х	Х	Х	High Z	High Z	Power down	Standby (I _{SB})
L	L	Н	L	L	Data Out	Data Out	Read – all bits	Active (I _{CC})
L	L	Н	L	Н	Data Out	High Z	Read – lower bits only	Active (I _{CC})
L	L	Н	Н	L	High Z	Data Out	Read – upper bits only	Active (I _{CC})
L	Х	L	L	L	Data In	Data In	Write – all bits	Active (I _{CC})
L	Х	L	L	Н	Data In	High Z	Write – lower bits only	Active (I _{CC})
L	Х	L	Н	L	High Z	Data In	Write – upper bits only	Active (I _{CC})
L	Н	Н	Х	Х	High Z	High Z	Selected, outputs disabled	Active (I _{CC})



Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C1041CV33-10BAJXE	001-85259	48-ball BGA (Pb-free)	Automotive-E

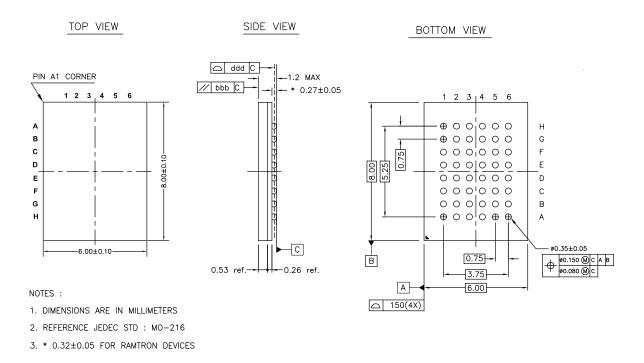
Ordering Code Definitions





Package Diagrams

Figure 8. 48-ball FBGA (6 × 8 × 1.2 mm) BA48M/BK48M (0.35 mm Ball Diameter) Package Outline, 001-85259



001-85259 *A



Acronyms

Acronym	Description
BHE	Byte High Enable
BLE	Byte Low Enable
CMOS	Complementary Metal Oxide Semiconductor
CE	Chip Enable
I/O	Input/Output
ŌĒ	Output Enable
SRAM	Static Random Access Memory
TTL	Transistor-Transistor Logic
VFBGA	Very Fine-Pitch Ball Grid Array
WE	Write Enable

Document Conventions

Units of Measure

Symbol	Unit of Measure			
°C	degree Celsius			
MHz	megahertz			
μΑ	microampere			
μs	microsecond			
mA	milliampere			
mm	millimeter			
ms	millisecond			
mV	millivolt			
mW	milliwatt			
ns	nanosecond			
%	percent			
pF	picofarad			
V	volt			
W	watt			



Document History Page

Document Title: CY7C1041CV33 Automotive, 4-Mbit (256 K × 16) Static RAM Document Number: 001-86495					
Revision	ECN	Orig. of Change	Submission Date	Description of Change	
**	3925192	TAVA	04/04/2013	New data sheet.	
*A	4103029	MEMJ	08/23/2013	Changed status from Preliminary to Final. Updated Ordering Information: No change in part numbers. Replaced "51-85087" with "001-85259" in "Package Diagram" column. Updated Package Diagrams: spec 001-85259 – Changed revision from ** to *A. Updated in new template.	
*B	4396000	VINI	06/02/2014	No technical updates. Completing Sunset Review.	
*C	4724503	PSR	04/14/2015	Updated Functional Description: Added "For a complete list of related resources, click here." at the end. Updated to new template. Completing Sunset Review.	
*D	6003585	AESATP12	12/22/2017	Updated logo and copyright.	



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